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電源管理



顯示驅動



二三極管



LDO穩壓器



觸摸芯片



MOS管



運算放大器



存儲芯片



MCU



串口通信

GBJ2506-TD

產品規格說明書



Features

- This series is UL listed under the Recognized Component Index, file number E142814
- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- High case dielectric strength of 1500VRMS
Ideal for printed circuit boards
- High surge current capability

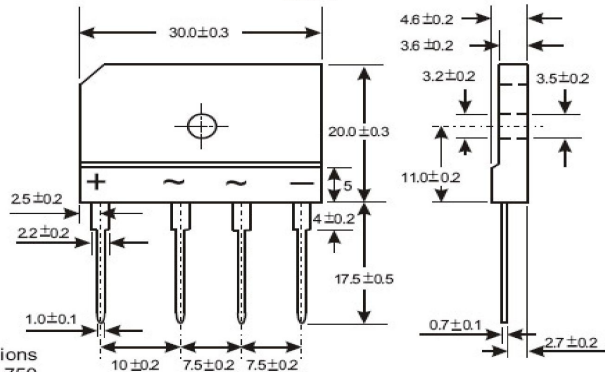
Mechanical Data

Case : Molded plastic body over passivated junctions
 Terminals : Plated leads solderable per MIL-STD-750, Method 2026
 Polarity : Polarity symbols molded on body
 Mounting Position : Any(3)
 Mounting Torque : 5 in-lbs max.
 Weight : 0.26 ounce, 7.0 grams (approx)

25 A Single-Phase Bridge Rectifier

Rectifier Reverse Voltage 50 to 1000V

GBJ6



Dimensions in millimeters(1mm =0.0394")

Maximum Ratings & Thermal Characteristics

Rating at 25°C ambient temperature unless otherwise specified, Resistive or Inductive load, 60 Hz.
 For Capacitive load derate current by 20%.

Parameter	Symbol	GBJ 25005	GBJ 2501	GBJ 2502	GBJ 2504	GBJ 2506	GBJ 2508	GBJ 2510	unit
Maximum repetitive peak reverse voltage	VRRM	50	100	200	400	600	800	1000	V
Maximum RMS bridge input voltage	VRMS	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	VDC	50	100	200	400	600	800	1000	V
Maximum average forward (with heatsink note1) rectified current at Tc=100°C (without heatsink)	IF(AV)	25.0 4.2							A
Peak forward surge current single sine-wave superimposed on rated load (JEDEC Method)	IFSM	350							A
Rating for fusing (t<8.3ms)	I ² t	510							A ² sec
Typical thermal resistance per element (note 1)	RthJC	1.0							°C / W
Operating junction and storage temperature range	TJ, TSTG	-55 to + 150							°C

Electrical Characteristics

Rating at 25°C ambient temperature unless otherwise specified. Resistive or Inductive load, 60Hz.
 For Capacitive load derate by 20 %.

Parameter	Symbol	GBJ 25005	GBJ 2501	GBJ 2502	GBJ 2504	GBJ 2506	GBJ 2508	GBJ 2510	Unit
Maximum instantaneous forward voltage drop per leg at 12.5 A	VF	1.05							V
Maximum DC reverse current at rated TA =25°C DC blocking voltage per element TA =125°C	IR	10.0 500							μA

Notes: (1) Device mounted on 250mm x 250mm x 20mm aluminum plate heatsink.

Rating and Characteristic Curves ($T_A=25^{\circ}\text{C}$ Unless otherwise noted) GBJ25005 thru GBJ2510

Fig. 1 Derating Curve for Output Rectified Current

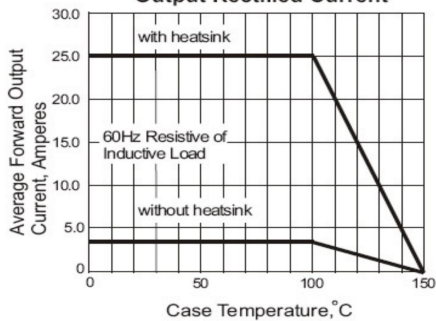


Fig. 2 Maximum Non-repetitive Peak Forward Surge Current

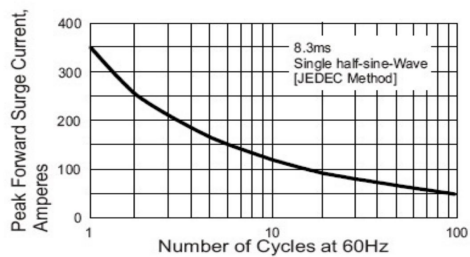


Fig. 3 Typical Instantaneous Forward Characteristics

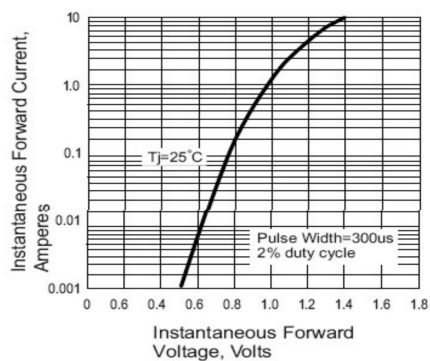


Fig. 4 Typical Reverse Characteristics at $T_j=25^{\circ}\text{C}$

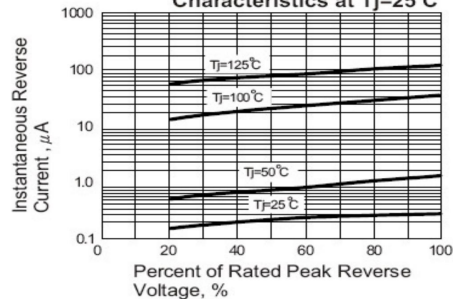


Fig. 5 Typical Junction Capacitance

